



浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

产品规格书

Specification of products

产品名称：整流管模块

产品型号：MDK55A1800V-T01

浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

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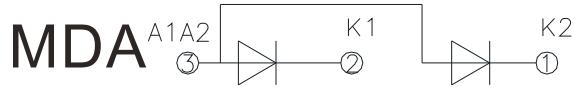
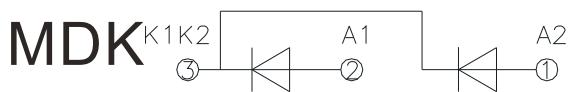
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拟制	审核	核准
林益龙	曹剑龙	宗瑞

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_J (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean for ward current	180° half sine wave 50Hz Single side cooled, $T_C = 100^\circ\text{C}$	150			55	A
$I_{F(RMS)}$	RMS for ward current	Single side cooled, $T_C = 100^\circ\text{C}$	150			86	A
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms $V_{RsM} = V_{DRM} \& V_{RRM} + 200\text{V}$	150	600		1800	V
I_{RRM}	Repetitive peak current	at V_{RRM}	150			8	mA
I_{FSM}	Surge forward current	10ms half sine wave	150			1.30	KA
I^2t	I^2t for fusing coordination	$V_R = 0.6V_{RRM}$				8.6	$\text{A}^2\text{s} \times 10^3$
V_{FO}	Threshold voltage		150			0.80	V
r_F	Forward slop resistance					3.47	$\text{m}\Omega$
V_{FM}	Peak for ward voltage	$I_M = 165\text{A}$	25			1.10	V
$R_{th(j-c)}$	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.700	$^\circ\text{C}/\text{W}$
V_{iso}	Isolation voltage	50Hz, RM. S, t=1min, $I_{iso} : 1\text{mA} (\text{max})$		2500			V
F_m	Terminal connection torque(M5)				4.0		N.m
	Mounting torque(M6)				5.0		N.m
T_{Stg}	Stored temperature			-40		125	$^\circ\text{C}$
W_t	Weight				110		g
Outline							

OUTLINE DRAWING & CIRCUIT DIAGRAM



Rating and Characteristic

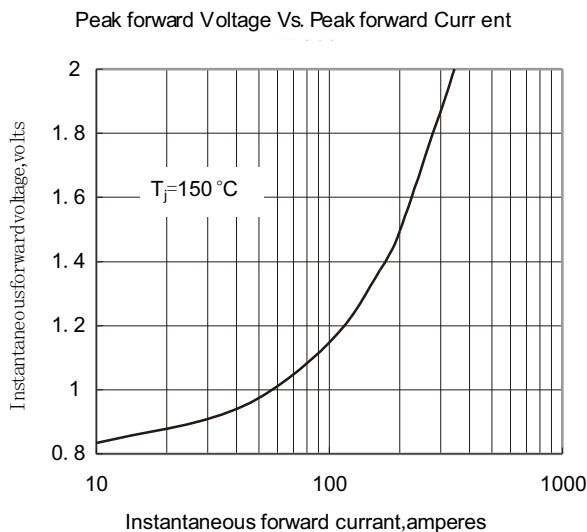


Fig. 1

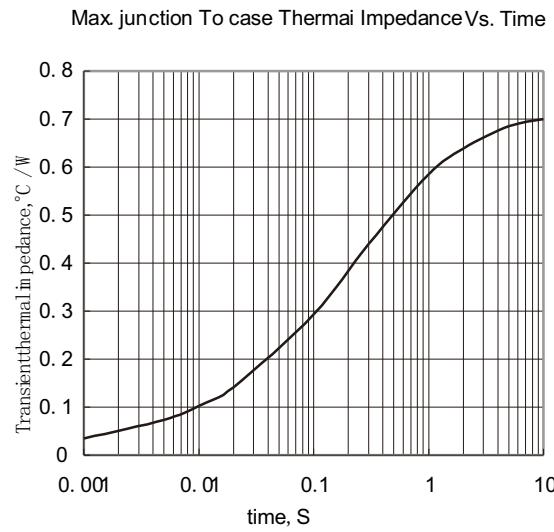


Fig. 2

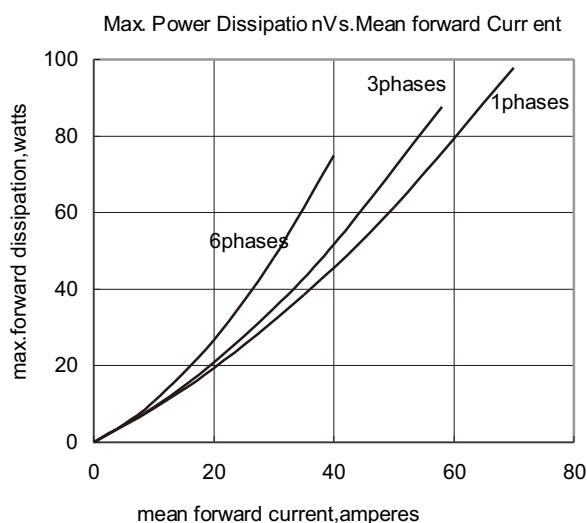


Fig. 3

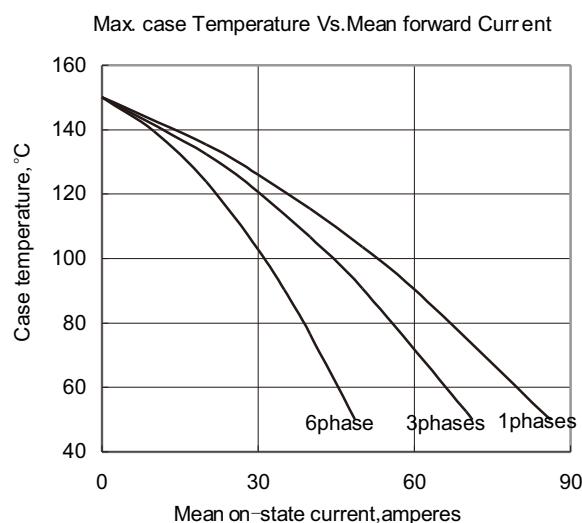


Fig. 4

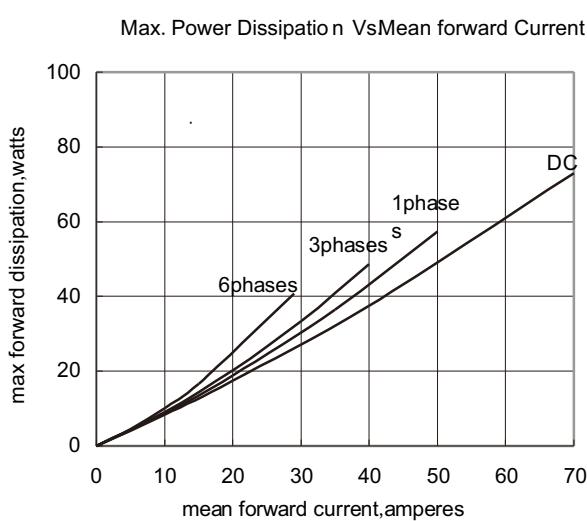


Fig. 5

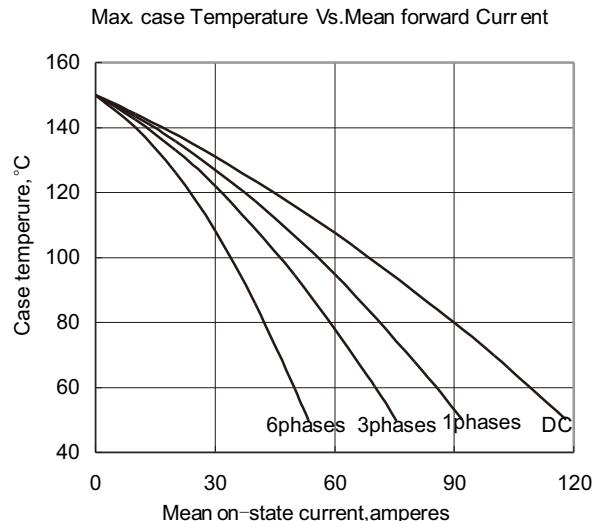


Fig. 6

Outside Dimension

